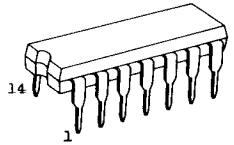
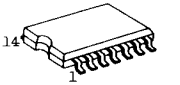
TC4001BP/TC4001BF QUAD 2 INPUT NOR GATE
TC4002BP/TC4002BF DUAL 4 INPUT NOR GATE
TC4025BP/TC4025BF TRIPLE 3 INPUT NOR GATE

The TC4001BP/BF, the TC4025BP/BF and TC4002BP/BF are 2-input, 3-input, 4-input positive NOR gate, respectively.

Since the outputs of these gates are equipped with the buffers, the input/output transmission characteristics have been improved and the variation of transmission time due to an increase in the load capacity is kept minimum.



DIP14(3D14A-P)

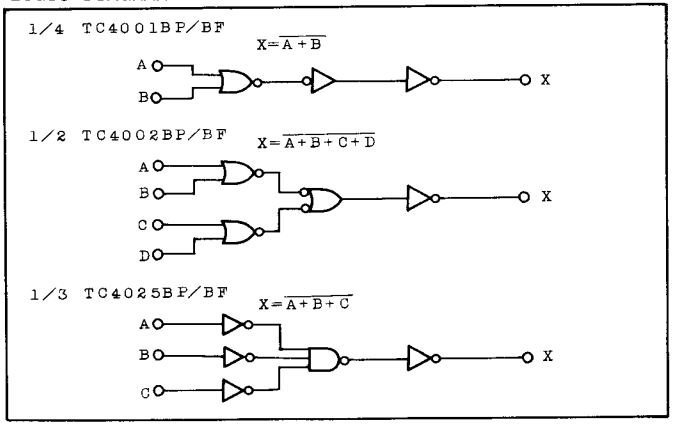


MFP14(F14GB-P)

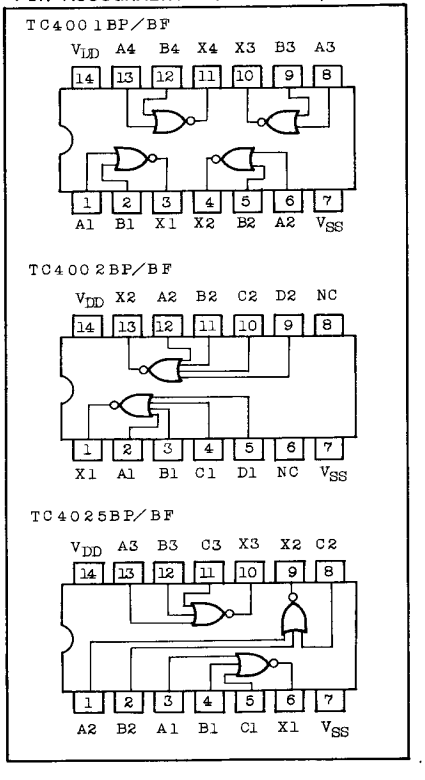
ABSOLUTE MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V_{DD}	V_{SS}-0.5 ∿ V_{SS}+20	V
Input Voltage	V_{IN}	V_{SS}-0.5 ∿ V_{DD}+0.5	V
Output Voltage	V_{OUT}	V_{SS}-0.5 ∿ V_{DD}+0.5	V
DC Input Current	I_{IN}	±10	mA
Power Dissipation	P_D	300(DIP)/180(MFP)	mW
Operating Temperature Range	T_A	-40 ∿ 85	°C
Storage Temperature Range	T_{stg}	-65 ∿ 150	°C
Lead Temp./Time	T_{sol}	260°C · 10 sec	

LOGIC DIAGRAM



PIN ASSIGNMENT (TOP VIEW)



RECOMMENDED OPERATING CONDITIONS (V_{SS}=0V)

CHARACTERISTICS	SYMBOL		MIN.	TYP.	MAX.	UNITS
DC Supply Voltage	V_{DD}		3	-	18	V
Input Voltage	V_{IN}		0	-	V_{DD}	V

STATIC ELECTRICAL CHARACTERISTICS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	V_{DD} (V)	-40°C MIN.	-40°C MAX.	25°C MIN.	25°C TYP.	25°C MAX.	85°C MIN.	85°C MAX.	UNITS
High-Level Output Voltage	V_{OH}	$\|I_{OUT}\|$<1μA	5	4.95	-	4.95	5.00	-	4.95	-	V
		$V_{IN}=V_{SS}$, V_{DD}	10	9.95	-	9.95	10.00	-	9.95	-	
			15	14.95	-	14.95	15.00	-	14.95	-	
Low-Level Output Voltage	V_{OL}	$\|I_{OUT}\|$<1μA	5	-	0.05	-	0.00	0.05	-	0.05	V
		$V_{IN}=V_{SS}$, V_{DD}	10	-	0.05	-	0.00	0.05	-	0.05	
			15	-	0.05	-	0.00	0.05	-	0.05	
Output High Current	I_{OH}	V_{OH}=4.6V	5	-0.61	-	-0.51	-1.0	-	-0.42	-	mA
		V_{OH}=2.5V	5	-2.5	-	-2.1	-4.0	-	-1.7	-	
		V_{OH}=9.5V	10	-1.5	-	-1.3	-2.2	-	-1.1	-	
		V_{OH}=13.5V	15	-4.0	-	-3.4	-9.0	-	-2.8	-	
		$V_{IN}=V_{SS}$									
Output Low Current	I_{OL}	V_{OL}=0.4V	5	0.61	-	0.51	1.2	-	0.42	-	
		V_{OL}=0.5V	10	1.5	-	1.3	3.2	-	1.1	-	
		V_{OL}=1.5V	15	4.0	-	3.4	12.0	-	2.8	-	
		$V_{IN}=V_{SS}$, V_{DD}									
Input High Voltage	V_{IH}	V_{OUT}=0.5V	5	3.5	-	3.5	2.75	-	3.5	-	V
		V_{OUT}=1.0V	10	7.0	-	7.0	5.5	-	7.0	-	
		V_{OUT}=1.5V,13.5V	15	11.0	-	11.0	8.25	-	11.0	-	
		$\|I_{OUT}\|$<1μA									
Input Low Voltage	V_{IL}	V_{OUT}=0.5V, 4.5V	5	-	1.5	-	2.25	1.5	-	1.5	
		V_{OUT}=1.0V, 9.0V	10	-	3.0	-	4.5	3.0	-	3.0	
		V_{OUT}=1.5V,13.5V	15	-	4.0	-	6.75	4.0	-	4.0	
		$\|I_{OUT}\|$<1μA									
Input Current "H" Level	I_{IH}	V_{IH}=18V	18	-	0.1	-	10^{-5}	0.1	-	1.0	μA
Input Current "L" Level	I_{IL}	V_{IL}=0V	18	-	-0.1	-	-10^{-5}	-0.1	-	-1.0	
Quiescent Device Current	I_{DD}	$V_{IN}=V_{SS}$, V_{DD}	5	-	0.25	-	0.001	0.25	-	7.5	
			10	-	0.5	-	0.001	0.5	-	15	
		*	15	-	1.0	-	0.002	1.0	-	30	

* All valid input combinations.

DYNAMIC ELECTRICAL CHARACTERISTICS (Ta=25°C, V_{SS}=0V, C_L=50pF)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V_{DD}(V)	MIN.	TYP.	MAX.	UNITS
Output Transition Time (TC4002BP/BF)	t_{TLH}		5	-	80	200	ns
			10	-	50	100	
			15	-	40	80	
Output Transition Time (TC4002BP/BF)	t_{THL}		5	-	80	200	
			10	-	50	100	
			15	-	40	80	
Output Transition Time (TC4001BP/BF), (TC4025BP/BF)	t_{TLH}		5	-	70	200	
			10	-	35	100	
			15	-	30	80	
Output Transition Time (TC4001BP/BF), (TC4025BP/BF)	t_{THL}		5	-	70	200	
			10	-	35	100	
			15	-	30	80	
Propagation Delay Time (TC4001BP/BF)	t_{pLH}		5	-	65	200	
			10	-	30	100	
			15	-	25	80	
Propagation Delay Time (TC4001BP/BF)	t_{pHL}		5	-	65	200	
			10	-	30	100	
			15	-	25	80	
Propagation Delay Time (TC4002BP/BF)	t_{pLH}		5	-	100	250	
			10	-	40	120	
			15	-	30	90	
Propagation Delay Time (TC4002BP/BF)	t_{pHL}		5	-	100	250	
			10	-	40	120	
			15	-	30	90	
Propagation Delay Time (TC4025BP/BF)	t_{pLH}		5	-	70	200	
			10	-	35	100	
			15	-	30	80	
Propagation Delay Time (TC4025BP/BF)	t_{pHL}		5	-	70	200	
			10	-	35	100	
			15	-	30	80	
Input Capacitance	C_{IN}			-	5	7.5	pF

CIRCUIT AND WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS